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Stocking Distributor

Click to view price, real time Inventory, Delivery & Lifecycle Information:

ON Semiconductor MJE521

For any questions, you can email us directly: <a href="mailto:sales@integrated-circuit.com">sales@integrated-circuit.com</a>



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# **MJE521**

# **Plastic Medium-Power NPN Silicon Transistor**

These devices are designed for use in general-purpose amplifier and switching circuits. Recommended for use in 5 to 10 Watt audio amplifiers utilizing complementary symmetry circuitry.

#### **Features**

- DC Current Gain  $h_{FE} = 40$  (Min) @  $I_C$ = 1.0 Adc
- Complementary to PNP MJE371
- Pb-Free Package is Available\*

#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	$V_{CEO}$	40	Vdc
Collector-Base Voltage	V <sub>CB</sub>	40	Vdc
Emitter Base Voltage	V <sub>EB</sub>	4.0	Vdc
Collector Current – Continuous – Peak	I <sub>C</sub>	4.0 8.0	Adc
Base Current – Continuous	I <sub>B</sub>	2.0	Adc
Total Power Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	P <sub>D</sub>	40 0.32	W mW/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-65 to +150	°C

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$\theta_{\sf JC}$	3.12	°C/W

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.



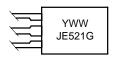
#### ON Semiconductor®

http://onsemi.com

# 4 AMPERES **POWER TRANSISTORS NPN SILICON** 40 VOLTS, 40 WATTS



#### MARKING DIAGRAM



= Year = Work Week JE521 = Device Code = Pb-Free Package

#### ORDERING INFORMATION

Device	Package	Shipping
MJE521	TO-225	500 Units/Box
MJE521G	TO-225 (Pb-Free)	500 Units/Box

MJE521/D

<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



# **Distributor of ON Semiconductor: Excellent Integrated System Limited**

Datasheet of MJE521 - TRANS NPN 40V 4A TO225AA

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# **MJE521**

## **ELECTRICAL CHARACTERISTICS** (T<sub>C</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS	•			
Collector–Emitter Sustaining Voltage (Note 1) $(I_C = 100 \text{ mAdc}, I_B = 0)$	V <sub>CEO(sus)</sub>	40	-	Vdc
Collector–Base Cutoff Current (V <sub>CB</sub> = 30 Vdc, I <sub>E</sub> = 0)	Ісво	-	100	μAdc
Emitter-Base Cutoff Current (V <sub>EB</sub> = 4.0 Vdc, I <sub>C</sub> = 0)	I <sub>EBO</sub>	-	100	μAdc
ON CHARACTERISTICS				
DC Current Gain (Note 1) (I <sub>C</sub> = 1.0 Adc, V <sub>CE</sub> = 1.0 Vdc)	h <sub>FE</sub>	40	-	-

<sup>1.</sup> Pulse Test: Pulse Width  $\leq 300 \,\mu\text{s}$ , Duty Cycle  $\leq 2.0\%$ .

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## **MJE521**

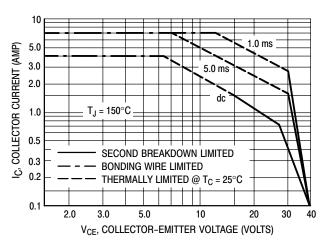


Figure 1. Active-Region Safe Operating Area

The data of Figure 1 based on  $T_{J(pk)} = 150^{\circ}\text{C}$ ;  $T_{C}$  is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided  $(T_{Jpk}) \leq 150^{\circ}\text{C}$ . At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate  $I_C - V_{CE}$  limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

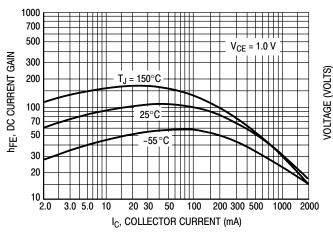


Figure 2. DC Current Gain

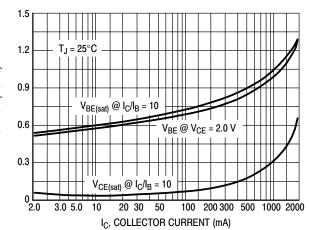


Figure 3. "On" Voltage

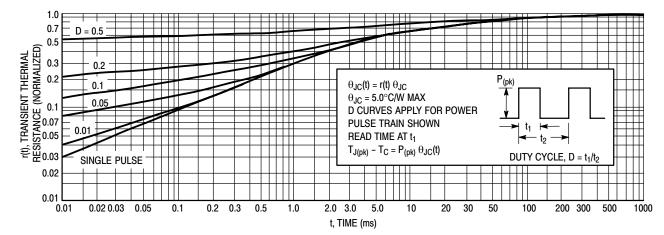


Figure 4. Thermal Response



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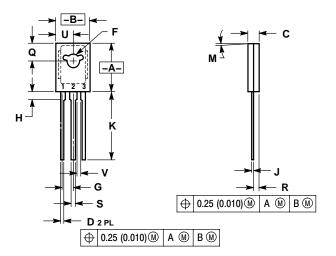
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#### PACKAGE DIMENSIONS

TO-225 CASE 77-09 **ISSUE Z** 



- NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCH.
  3. 077-01 THRU -08 OBSOLETE, NEW STANDARD 077-09.

	INCHES		INCHES MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.425	0.435	10.80	11.04
В	0.295	0.305	7.50	7.74
С	0.095	0.105	2.42	2.66
D	0.020	0.026	0.51	0.66
F	0.115	0.130	2.93	3.30
G	0.094 BSC		2.39 BSC	
Н	0.050	0.095	1.27	2.41
J	0.015	0.025	0.39	0.63
K	0.575	0.655	14.61	16.63
M	5° TYP		5°TYP	
Q	0.148	0.158	3.76	4.01
R	0.045	0.065	1.15	1.65
S	0.025	0.035	0.64	0.88
U	0.145	0.155	3.69	3.93
٧	0.040		1.02	

STYLE 1: PIN 1. EMITTER

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